

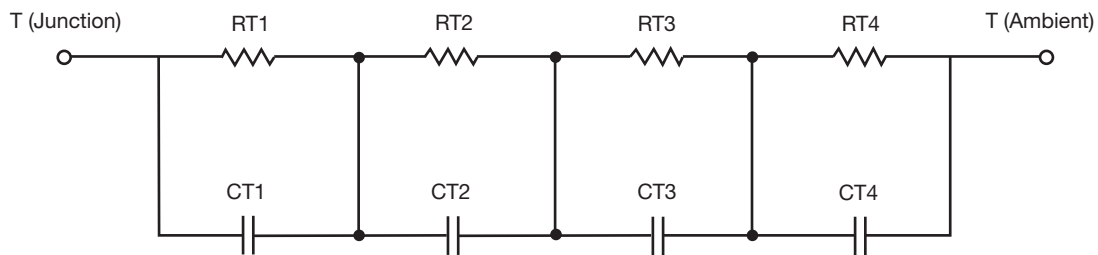
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION

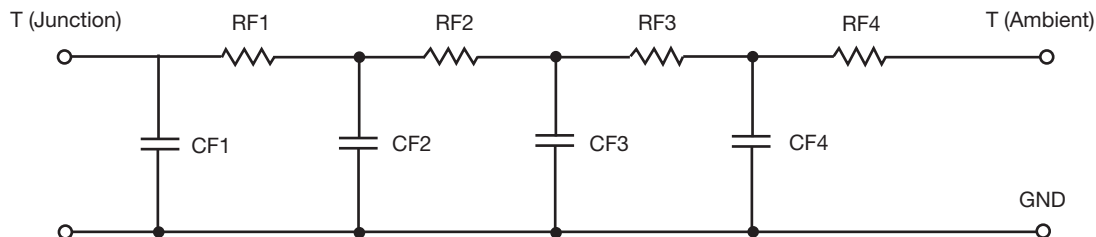


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	N/A	2.4639	N/A
RT2	N/A	357.5286m	N/A
RT3	N/A	941.0714m	N/A
RT4	N/A	1.2375	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	N/A	14.3869m	N/A
CT2	N/A	487.9736u	N/A
CT3	N/A	65.3439m	N/A
CT4	N/A	3.1006m	N/A

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION

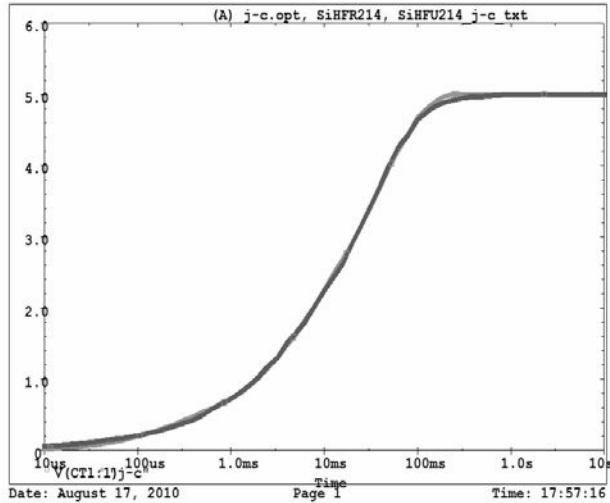
R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	N/A	735.1676m	N/A
RF2	N/A	1.7248	N/A
RF3	N/A	2.2588	N/A
RF4	N/A	281.2324m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	N/A	538.8377u	N/A
CF2	N/A	2.9557m	N/A
CF3	N/A	10.5115m	N/A
CF4	N/A	361.4589m	N/A

Note

N/A indicates not applicable



SiHFR214, SiHFU214 Tank j-c Temperature: 27.0



SiHFR214, SiHFU214 Filter j-c Temperature: 27.0

